

# Application of the spectral response of photoluminescence in photovoltaics

Never Stand Still

Engineering

The Student:

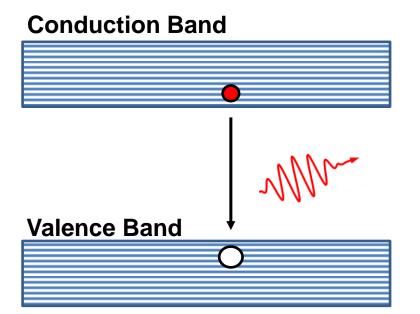
Mattias Juhl

The Supervisors:

Professor Thorsten Trupke Scientia Profesor Martin Green

# Photoluminescence?

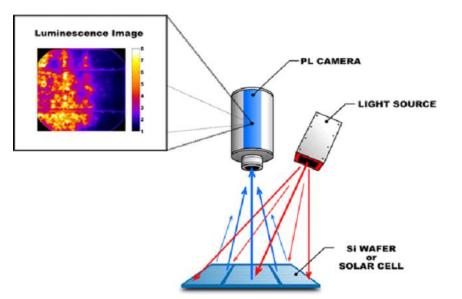
- Luminescence: Radiative recombination of excess carriers
- Photo  $\rightarrow$  generated by light
- Why photoluminescence?





# Photoluminescence?

- Luminescence: Radiative recombination of excess carriers
- Photo  $\rightarrow$  generated by light
- Why photoluminescence?
- How do I measure
   photoluminescence?
- What am I doing that's new?

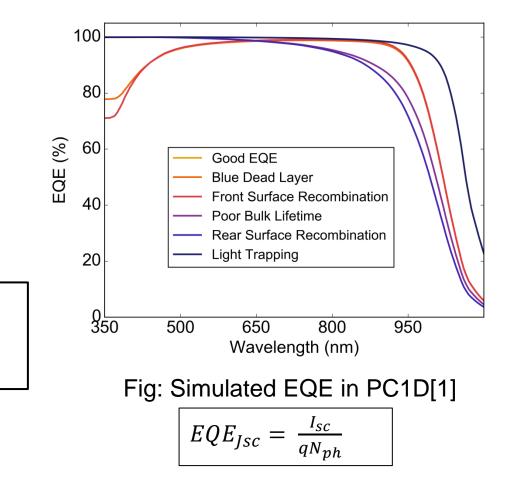




## Spectral response

- The spectral response determines wavelength dependent properties
- That is a lot of Information
- Si's Photoluminescence only at 900 - 1300 nm

Lets change the illumination wavelength and measure photoluminescence



1. D.A. Clugston and P.A. Basore, Conf. Rec. Twenty Sixth IEEE Photovolt. Spec. Conf.-1997

#### Application 1: Band-to-band absorptance



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$$I_{PL} \propto \Delta n N_d \qquad \tau = \frac{\Delta n}{G}$$
$$I_{PL} \propto G \tau$$

For a constant effective lifetime

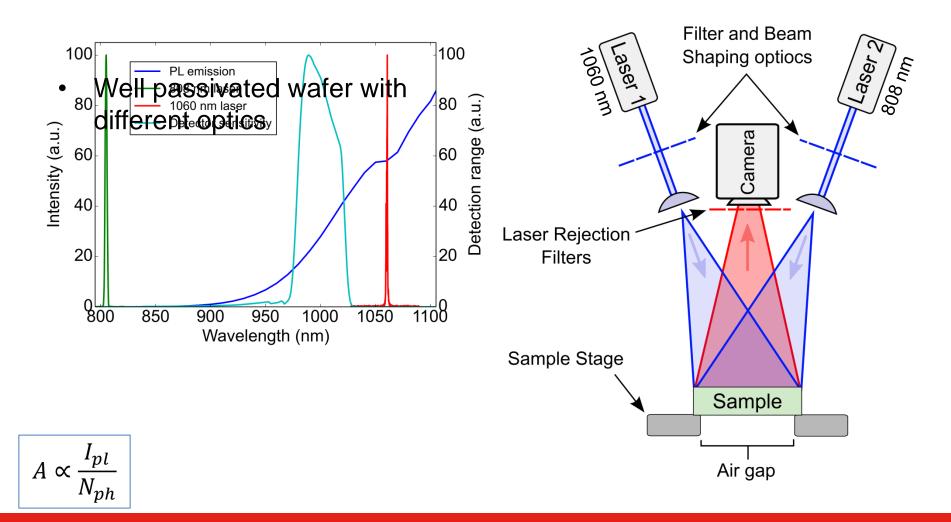
 $I_{PL} \propto G$ 

 $\propto AN_{ph}$ 

$$\frac{I_{pl}}{N_{ph}} \propto A$$



# Application 1: Band-to-band Absorptance

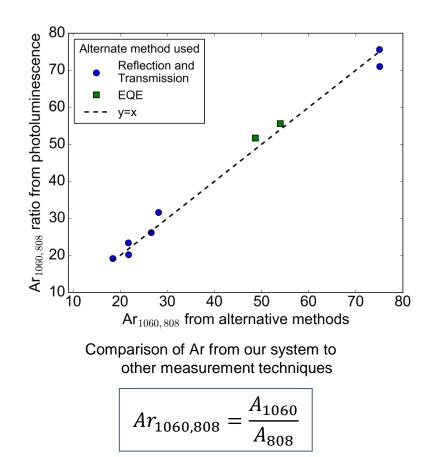


[1] Juhl, M. K., Trupke, T., Abbott, M., & Mitchell, B. (2015). *IEEE Journal of Photovoltaics*, *5*(6), 1840–1843.
[2] Juhl, M. K., et at. (2015) *31st European Photovoltaic Solar Energy Conference* Hamburg.



# Application 1: Band-to-band Absorptance

- Well passivated wafer with different optics
- Compared to:
  - 1. Optical measurements
  - 2. EQE measurements

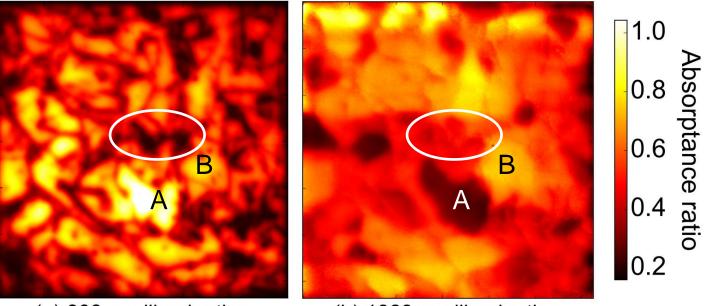


$$A \propto \frac{I_{pl}}{N_{ph}}$$

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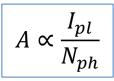


#### Application 1: Absorptance imaging!



(a) 808 nm illumination

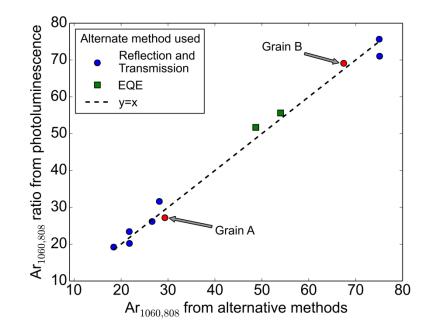
(b) 1060 nm illumination





# Application 1: Band-to-band Absorptance

- Well passivated wafer with different optics
- Compared to:
  - 1. Optical measurements
  - 2. EQE measurements



**1**pl  $A \propto -$ 

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It works!!

#### Application 2: External Quantum Efficiency



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$$EQE_{JSC} = \frac{I_{SC}}{qN_{ph}}$$

$$EQE_{jsc} \propto \frac{e^{\frac{V_{oc}}{Vt}}}{N_{ph}} \qquad I_{PL} \propto e^{\frac{iV_{oc}}{Vt}}$$

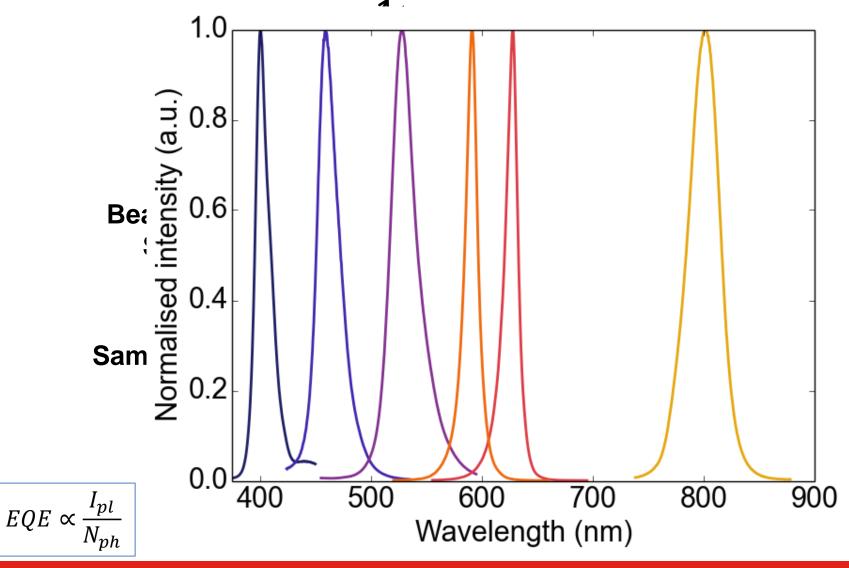
In low injection:

$$EQE_{Jsc} \propto \frac{I_{pl}}{N_{ph}}$$

$$\frac{I_{pl}}{N_{ph}}$$
 is proportional to the EQE

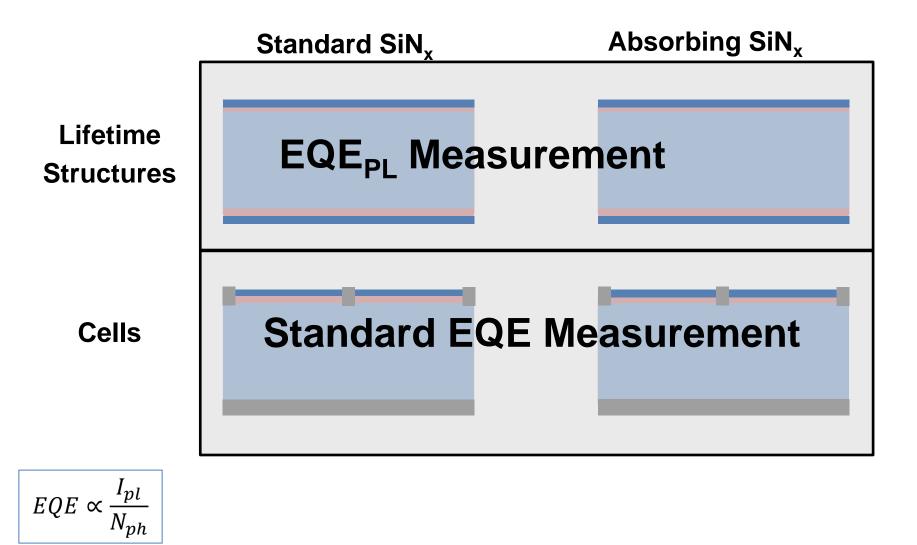


## The Experimental Setup



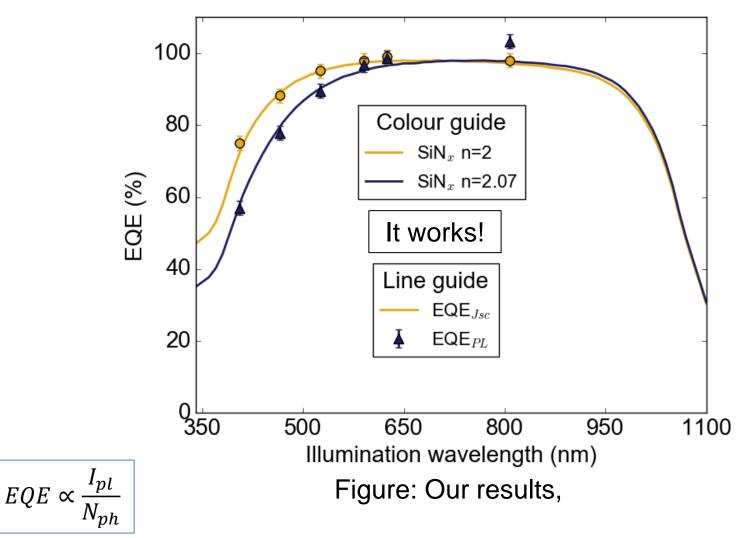


## The Experiment





## The Result





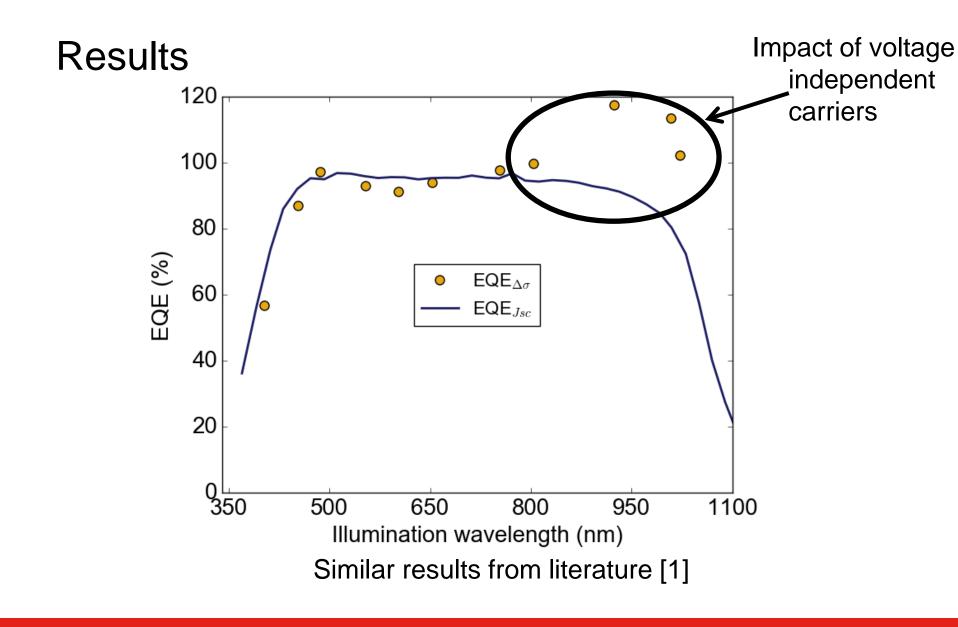
# **Conclusions for applications!**

Can determine:

- The band-to-band absorptance, with imaging!
- The external quantum efficiency

But EQE<sub>PL</sub> didn't match with EQE<sub>isc</sub> at  $\approx$  800 nm.





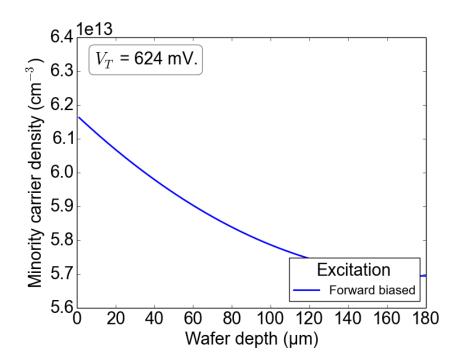


It wasn't me![1]

Voltage dependent carriers:

Depend on the junction voltage

Voltage independent carriers:



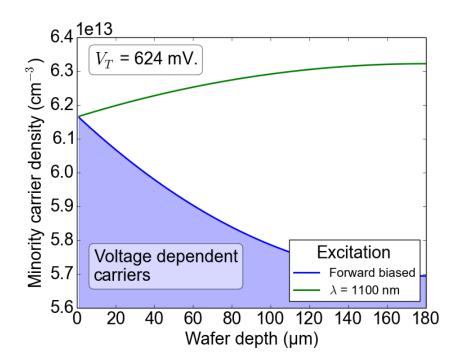


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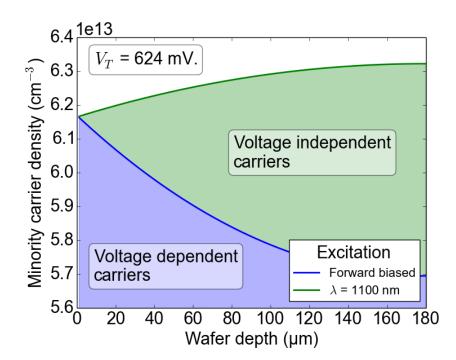


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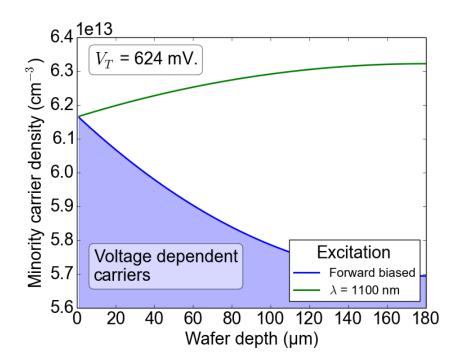


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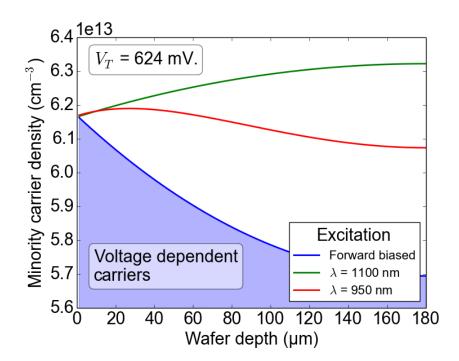


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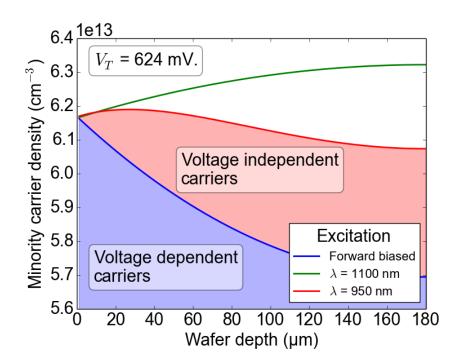


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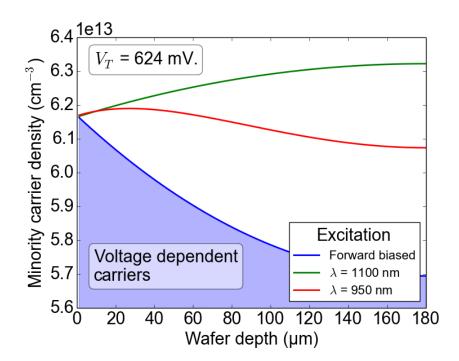


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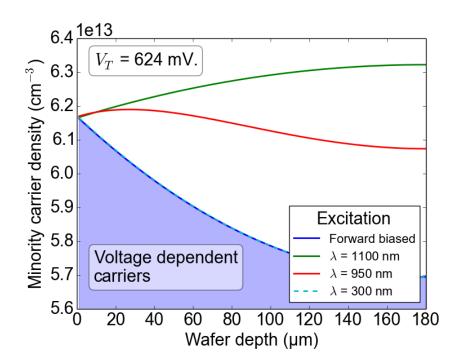


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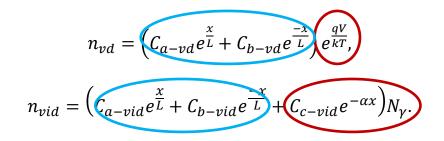
#### Voltage independent carriers

Steady State Continuity Equation!

$$\frac{d^2 n[x]}{dx^2} = \frac{n[x]}{L^2} - \frac{\alpha N_{\gamma} e^{-\alpha x}}{D}$$
$$n = C_a e^{\frac{x}{L}} + C_b e^{-\frac{x}{L}} + C_c e^{-\alpha x},$$

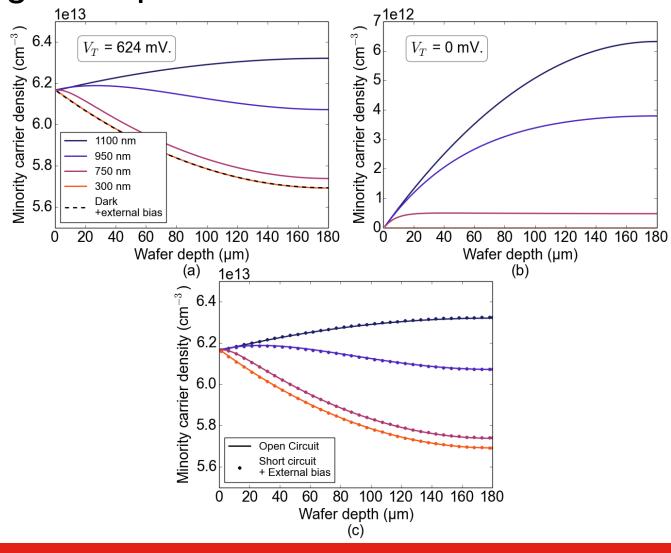
Inhomogeneous differential equation!:

 $n = n_{vd} + n_{vid},$ 





#### Voltage independent carriers

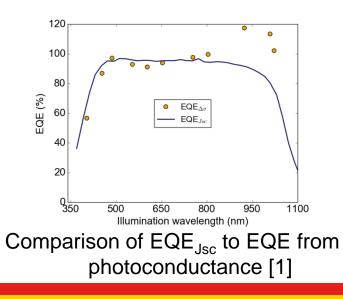


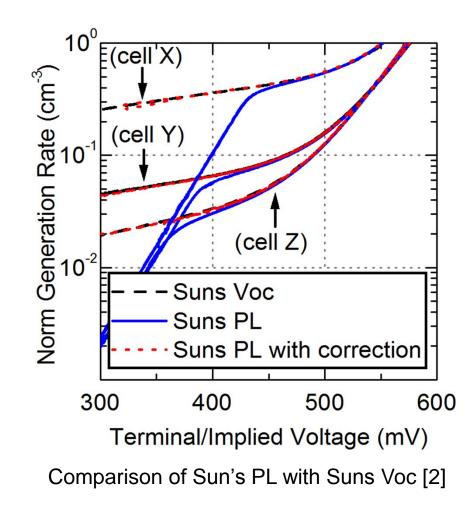


# The impact

Cause's error when caculating

- Implied voltage from lifetime
- Lifetime from voltage
- Absorptance from average excess carrier density





[1] Mäckel, H., & Cuevas, A. (2001). In *International Solar Energy Society Solar World Congress*. Adelaide [2] Abbott, M. D., Bardos, R. A., Trupke, *et.al.* (2007). *Journal of Applied Physics*, *10*2(4), 44502.



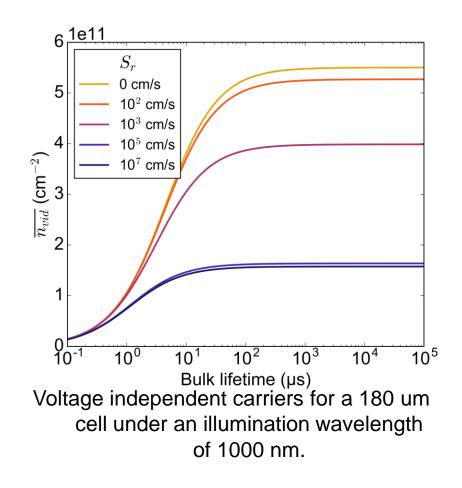
#### The impact: When does it happen

• It's complicated

$$n = n_{vd} + n_{vid},$$

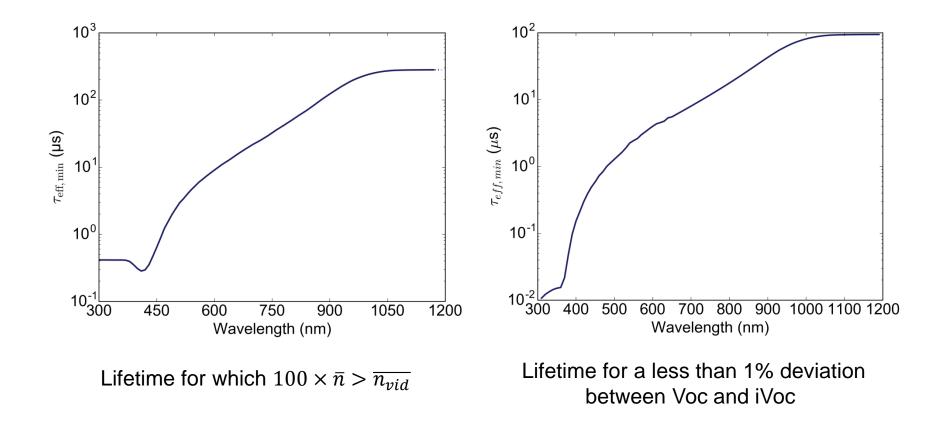
• So how do the  $n_{vid}$  behave?

$$\tau_{eff,min} = \frac{100 \times \overline{n_{vid}}}{G}$$





#### The impact: When does it happen

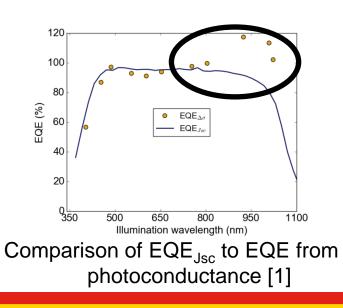


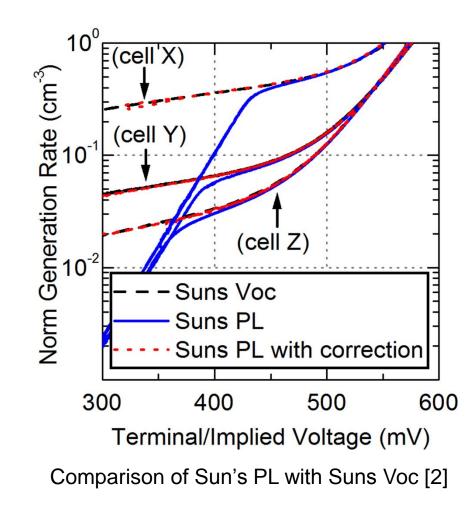


# The impact

Cause's error when caculating

- Implied voltage from lifetime
- Lifetime from voltage
- Absorptance measurements





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## Conclusions

- PL  $\rightarrow$  well passivated samples  $\rightarrow$  Band-to-band absorptance
- $PL \rightarrow$  no voltage independent carriers $\rightarrow$  EQE
- The carrier density can be described in terms of a voltage dependent and independent term.
- Conversion from Voltage to lifetime does not always work.

# Thank You!

